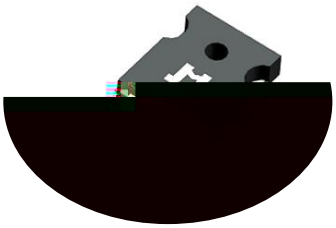
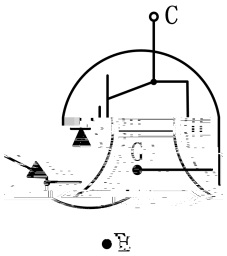
- V_{CE} =1200V
- I_C=50A@T_C=100
- $V_{CE(sat)}$=1.7V

TO-247





- Trench and field-stop technology
- High speed switching
- Low collector to emitter saturation voltage
- Easy parallel switching capability
- Short circuit withstands time 10μs
- High ruggedness performance
- RoHS compliant

- Inverter
- Motor driver

Type	Marking	Package	Packaging Method
JJT50N120SE	T50120SE	TO-247	Tube

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(T_{vj}=25 unless otherwise specified)

V_F	Diode forward voltage	I_F=50A	-	2.2	-	V
		I_F=50A T_{vj}=175	-	1.8	-	V
t_{rr}	Diode reverse recovery time	V_R=600V I_F=50A di_F/dt=-750A/μs	-	174	-	ns
I_{rrm}	Diode peak reverse recovery current		-	25	-	A
Q_{rr}	Diode reverse recovery charge		-	2096	-	nC
t_{rr}	Diode reverse recovery time	V_R=600V I_F=50A di_F/dt=-750A/μs T_{vj}=175	-	299	-	ns
I_{rrm}	Diode peak reverse recovery current		-	39	-	A
Q_{rr}	Diode reverse recovery charge		-	5731	-	nC

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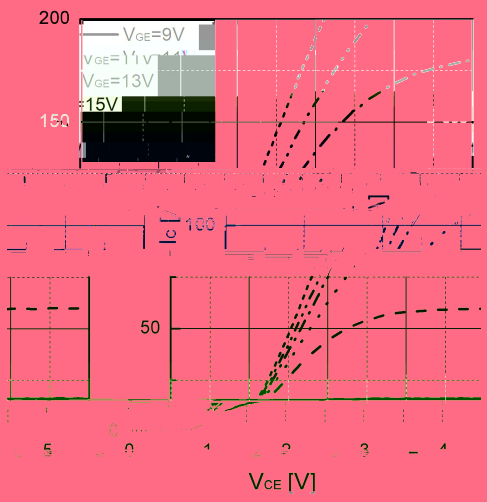


Fig 1. Typical output characteristic (T_{vj}=25)

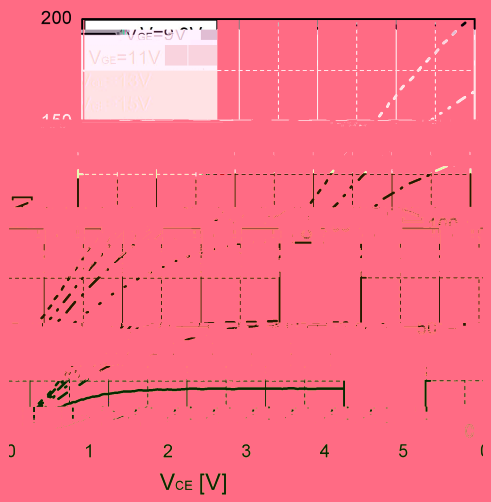


Fig 2. Typical output characteristic(T_{vj}=175)

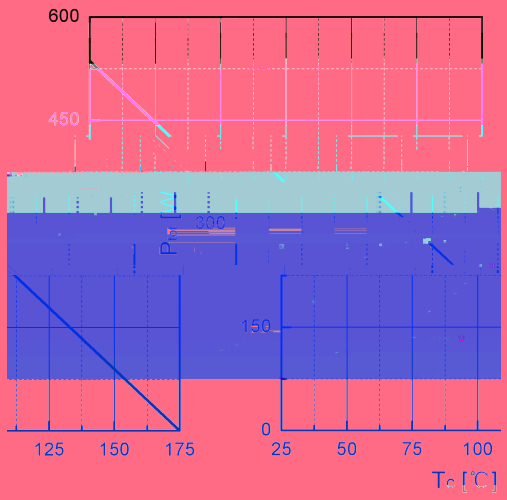


Fig 3. Power dissipation as a function of T_C

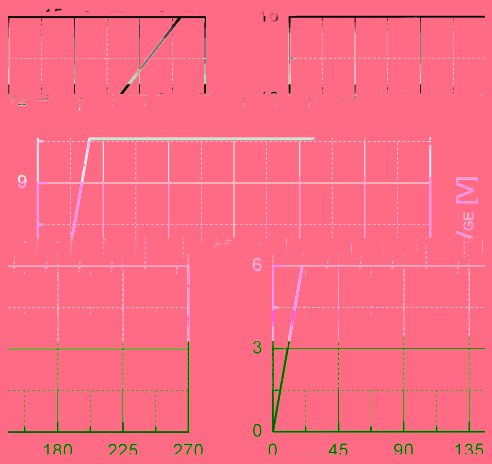


Fig 4. Typical Gate charge

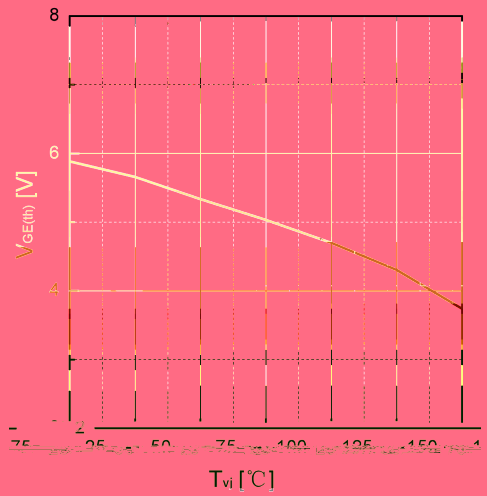


Fig 5. Typical $V_{GE(th)}$ as a function of T_{vj} (I_C=1mA)

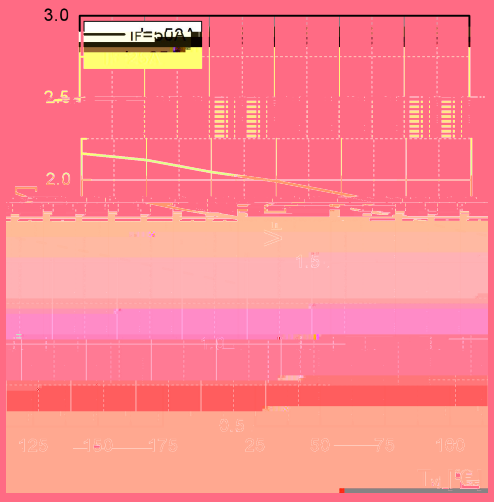


Fig 6. Typical V_F as a function of T_{vj}

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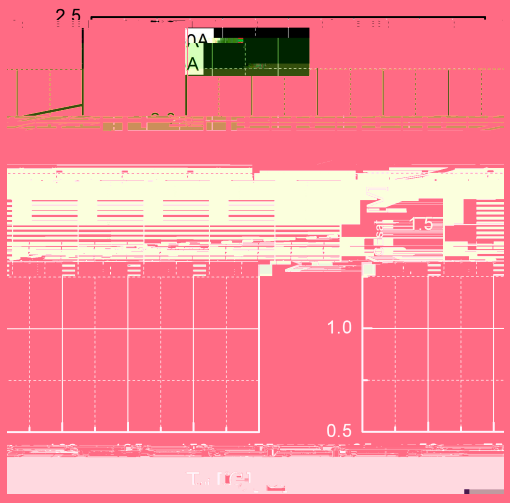


Fig 7. Typical V_{CEsat} as a function of T_{vj}

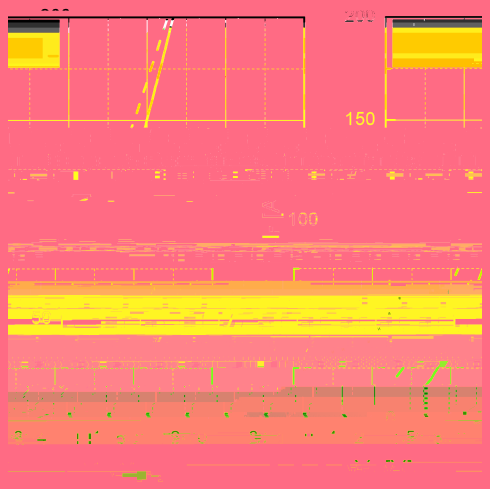


Fig 8. Typical I_F as a function of V_F

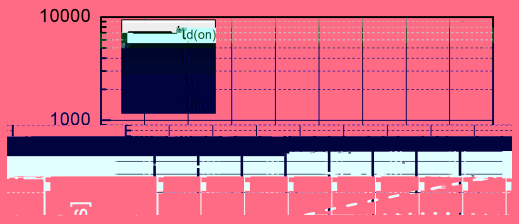


Fig 9. Typical switching time as a function of I_C

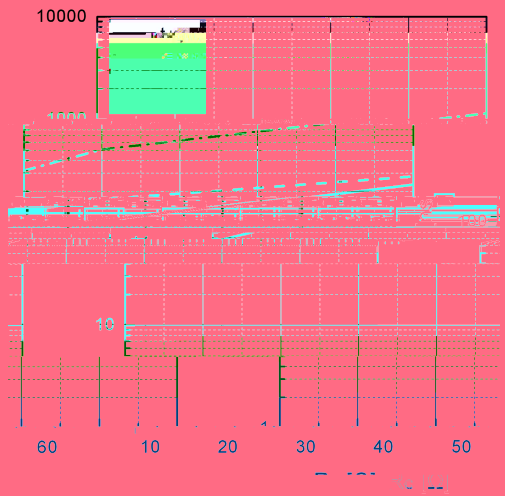


Fig 10. Typical switching times as a function of R_G

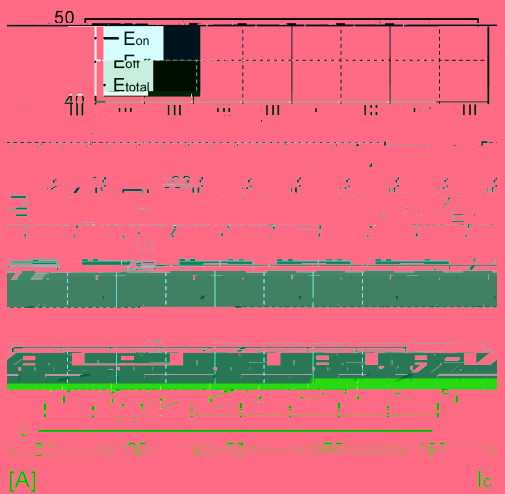


Fig 11. Typical switching energy losses as a function of I_C

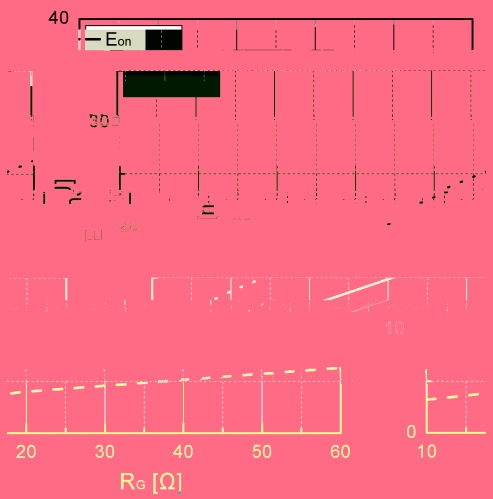


Fig 12. Typical switching energy losses as a function of R_G

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Date	Revision	Changes
2025-04-08	Rev 1.0	Release of the preliminary datasheet.
2025-04-30	Rev 1.1	Add graph and character update

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